# OCXO (Oven Controlled Crystal Oscillators) OC149E3A, OC149E3S Series

## +3.3 V Sine Wave



#### **Features:**

- Full size 4 pin DIP full metal package
- +3.3 V D.C supply Voltage
- 50 ohm load Sine wave output
- Choice of AT-cut or SC-cut crystal
- Voltage control (Electronic Frequency Tuning) on pin 1



**General Specifications:** 

<u> General (</u>	spec	<u>ifications</u> :				
Output Wave From			Sine wave. Wave form code is "E"			
Type of Crystal Cut Used			AT-cut crystal: 8.0 MHz ~125.0 MHz			
			SC-cut crystal: 10.0 MHz ~ 100.0 MHz			
			AT-cut. Use "A" for crystal code. SC-cut. Use "S" for crystal code			
			Please refer to technical note TN031 for SC and AT-cut crystal comparison			
Supply Voltage (V <sub>DD</sub> )		(V <sub>DD</sub> )	+3.3 V (voltage code is "3")			
Initial Calibration Tolerance		on Tolerance	AT-cut: $\pm 0.5$ ppm max. at the time of shipment. @ $+25^{\circ}$ C, Vcon= $+1.65$ V SC-cut: $\pm 0.05$ ppm max. at the time of shipment. @ $+25^{\circ}$ C, Vcon= $+1.65$ V			
			AT-cut crystal	SC-cut crystal		
Ą	Ope	rating Temperature Range	$\pm 0.05$ ppm over -20°C to +70°C $\pm 0.1$ ppm over -20°C to +70°C $\pm 0.3$ ppm over -20°C to +70°C	$\pm 0.02$ ppm over -20°C to +70°C		
Frequency Stability vs	(custom spec. on request)		±0.1 ppm over -40°C to +85°C ±0.5 ppm over -40°C to +85°C ±1.0 ppm over -40°C to +85°C	±0.05 ppm over -40°C to +85°C		
	Long Term Aging		AT-cut: $\pm 0.7$ ppm typical for 20 MHz; first year. After 30 day power on. SC-cut: $\pm 0.3$ ppm typical for 20 MHz; first year. After 30 day power on.			
	Supply Voltage ±5% Variation		AT-cut: ±30 ppb typical ; SC-cut: ±20 ppb typical			
	Load ±5% variation		AT-cut: ±30 ppb typical ; SC-cut: ±20 ppb typical			
l on	Electronic Frequency Control (EFC at pin 1) Control Voltage Range		AT-cut: ±5.0 ppm typical; SC-cut: ±1.0 ppm typical			
ate -			0.3 V to 3.0 V			
Voltage Control on	Transfer Function		Positive: Increasing control voltage increases output frequency			
oltag	Input Impedance		100 K Ω min.			
>	EFC Linearity		±10% max.			
Power	Pnw	er Dissipation	Steady-state: 250 mA max. at +25°C.			
	LAMEI DISSIHATIANI		Warm-up: 650 mA max.			
	Warm-up time (at +25°C)		AT-cut: 3 minutes max. Within $\pm 0.1$ ppm of the unit output frequency. SC-cut: 2 minutes max. Within $\pm 0.1$ ppm of the unit output frequency.			
	Output Wave Form		Sine Wave			
Output	Output Load		50 Ω typical			
output	Output Level		5 dBm min.			
	Harmonic Attenuation		-25 dB max.			

### MERCURY <u>www.mercury-crystal.com</u>

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MERCURY	Page 1 of 2	Date: March 16, 2020	Rev. b1
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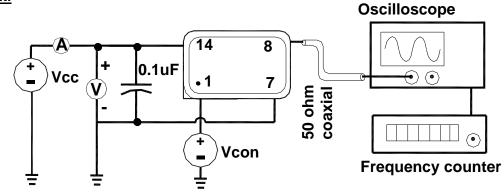
# $\underline{O}$ ven $\underline{C}$ ontrolled $\underline{C}$ rystal $\underline{O}$ scillators Wave Form: TTL / CMOS Square Wave



MERCURY Since 1973

	Spuriou	s Attenuation	-75 dB max.					
	Phase	Offset	10 Hz	100 Hz	1 KHz	10 KHz		
	Noise	10 MHz AT-cut Crystal	-80 dBc typ.	-120 dBc typ.	-145 dBc typ.	-150 dBc typ.		
Storage 1	Storage Temperature			-40°C to +85°C				
Shock			2000 G's, 0.3 ms ½ sine					
Vibration	Vibration			10 to 2000 Hz / 10 G's				

### OC149E3 Test Circuit:

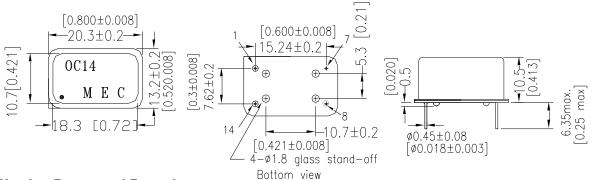


#### **OC149E3 Package Dimensions and Pin Connections:**

unit mm [inches]

Pin 1: Voltage Control Pin 7: Ground / Case Pin 8: Output Pin 14: Supply Voltage

Square corner is pin No. 1



### **Part Number Format and Example**:

<b>Example</b> : 0C149E3A-10.000-0.1/-20+70							
OC149E3	Α	_	10.000	_	0.1	/	-20+70
0	2	dash	<b>6</b>	dash	4	slash	6
1. OC149E3: OC149 series; "E" for 50 ohm load sine wave; "3" for +3.3 V supply voltage							

2: Crystal type. "A" for AT-cut crystal; "S" for SC-cut crystal 3: Frequency in MHz

**4**: Frequency stability in ppm **5**: Operating temperature range in Celsius

MERCURY	Page 2 of 2	Date: March 16, 2020	Rev. b1